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PPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/708,035	02/04/2004	Laertis Economikos	FIS920030391	2034	
30449 75	90 06/30/2006		EXAMINER		
	OLSEN & WATTS	VU, DAVID			
22 CENTURY I SUITE 302	HILL DRIVE	ART UNIT	PAPER NUMBER		
LATHAM, NY 12110			2818		
			DATE MAILED: 06/30/2000	6	

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary		Ap	Application No. Applicant(s)					
		10	0/708,035		ECONOMIKOS ET AL.			
		Ex	aminer		Art Unit			
		DA	AVID VU		2818			
Period fo	The MAILING DATE of this commu or Reply	nication appears	s on the cover shee	et with the c	orrespondence ad	ldress		
WHIC - Exter after - If NO - Failu Any I	ORTENED STATUTORY PERIOD IN CHEVER IS LONGER, FROM THE IN ISSUMED IN ITS	MAILING DATE s of 37 CFR 1.136(a). munication. statutory period will ap y will, by statute, caus	OF THIS COMMU In no event, however, ma ply and will expire SIX (6) se the application to become	JNICATION ay a reply be tim MONTHS from ne ABANDONED	l. ely filed the mailing date of this c O (35 U.S.C. § 133).			
Status								
1)⊠	Responsive to communication(s) fil	ed on 11 April :	2006.					
2a)□	This action is FINAL . 2b)⊠ This action is non-final.							
3)□								
	closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.							
Dispositi	on of Claims							
4)⊠	4) Claim(s) 1-20 is/are pending in the application.							
	4a) Of the above claim(s) <u>1-10</u> is/are withdrawn from consideration.							
5)	<u> </u>							
6)⊠	Claim(s) 11-20 is/are rejected.							
7)	Claim(s) is/are objected to.							
8)⊠	Claim(s) <u>1-20</u> are subject to restrict	tion and/or elec	tion requirement.					
Applicat	on Papers							
9)[The specification is objected to by t	he Examiner.						
10)⊠	10)⊠ The drawing(s) filed on <u>04 February 2004</u> is/are: a)⊠ accepted or b)□ objected to by the Examiner.							
	Applicant may not request that any obj	ection to the drav	ving(s) be held in ab	eyance. See	e 37 CFR 1.85(a).			
	Replacement drawing sheet(s) including	=						
11)	The oath or declaration is objected	to by the Exam	iner. Note the atta	ched Office	Action or form P	TO-152.		
Priority (ınder 35 U.S.C. § 119							
 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 								
2) Notice 3) Information	t(s) se of References Cited (PTO-892) se of Draftsperson's Patent Drawing Review of Dramation Disclosure Statement(s) (PTO-1449 of the Drawing Date		Paper 5) Notice	iew Summary · No(s)/Mail Da e of Informal P :		O-152)		

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DETAILED ACTION

Election/ Restriction

1. Applicant's election of Species II (Claims 11-20) filed on 04/11/06 is acknowledged. The traverse is on the ground(s) that "the search and examination of the entire application can be made without serious burden". This is not found persuasive because the numerous species each include non-obvious variants which would be a burden in both search and examination.

The requirement is still deemed proper and is therefore made FINAL.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

2. Claims 11-13, 16 and 18-19 are rejected under 35 U. S. C. 102(e) as being anticipated by Heo et al. (US Pat. 6,756,654, hereinafter Heo).

Heo in figs. 4, 5 and 8 disclose a method of fabricating a filled trench structure, comprising:

(a) forming a planarization stop layer 120 on a top surface of a substrate 100;

(b) forming a first set of trenches in a first region 1 of planarization stop layer and substrate and forming a second set of trenches in a second region 2 of planarization stop layer and substrate, trenches in first set of trenches having a higher aspect ratio than trenches in second region (col. 8, lines 35-38);

- (c) depositing a fill material 170 in first and second set of trenches and on a top surface of planarization stop layer, fill material completely filling trenches (col. 7, lines 1-24);
- (d) removing an upper portion of said fill material; and (e) removing, using a planarization process, all fill material from top surface of planarization stop layer, a top surface of fill material in first and second sets of trenches co-planer with top surface of planarization stop layer (col. 7, lines 24-35 and fig. 8).

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out

the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

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3. Claims 14, 15, 17 and 20 are rejected under 35 U.S.C. 103 (a) as being unpatentable over Heo (US Pat. 6,756,654) in view of Kuroi et al. (US Pat. 5,889,335, hereinafter Kuroi).

Regarding claims 14 and 17, Heo discloses a process of forming a filled trench structure but fails to disclose the step of masking the second region. However, Kuroi teaches in col. 14, lines 37-50 and figs. 2-4 that forming a mask layer 51 on fill material 2 in second region (peripheral circuit area 11C), wherein the fill material 2 is only removed from first region (memory cell area 11B); and then removing masking layer 51. It would have been obvious to one with ordinary skill in the art at the time of the invention to form a filled trench structure as taught by Kuroi in the process of Heo in order to keep the surface of the insulation layer (the fill material) even with the surface of the silicon nitride (planarization stop layer) (see Kuroi; col. 7, line 63 through col. 8, line 5).

Regarding claims 15 and 20, the combination of Heo and Kuroi fails to disclose the fill material is removed about 5 to 20% of the as deposited thickness. It would have been obvious to one with ordinary skill in the art at the time of the invention to performing dry etch/remove step as taught by Kuroi. The amount of the fill material being etched does not define patentable over Kuroi since it is well known processing variable and the discovery of the optimum or workable range involves only routine skill in the art. The specific amount of the semiconductor being etched does not provide any critical or unexpected results to the method of manufacturing a

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bipolar transistor device. Rather, it is merely an obvious selection of the etching amount based on desired functional characteristics determinable by routine experimentation. In Aller, the court stated, "Where the general conditions of a claim are disclosed in the prior art, it is not inventive to discover the optimum or workable ranges by routine experimentation." *In re Aller*, 220 F.2d 454, 456 105 USPQ 233,235 (CCPA 1995).

Conclusion

4. Any inquiry concerning this communication or earlier communications from the examiner should be directed to David Vu whose telephone number is (571) 272-1798. The examiner can normally be reached on Monday-Friday from 8:00am to 5:00pm. If attempt to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Matthew Smith S can be reached on (571) 272-1907. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR, Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

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